

256 x 9, 512 x 9, 1K x 9, 2K x 9, 4K x 9 Cascadable FIFO

Features

- 256 x 9, 512 x 9, 1,024 x 9, 2048 x 9, and 4096 x 9 FIFO buffer memory
- Dual-port RAM cell
- · Asynchronous read/write
- High-speed 50.0-MHz read/write independent of depth/width
- Low operating power
 I_{CC1} = 35 mA
- Half Full flag in standalone
- Empty and Full flags
- Retransmit in standalone
- Expandable in width and depth
- Parallel cascade minimizes bubble-through
- 5V ± 10% supply
- 300-mil DIP packaging
- 7x7 TQFP
- 300-mil SOJ packaging
- TTL compatible
- Three-state outputs
- Pin compatible and functional equivalent to IDT7200, IDT7201, IDT7202, IDT7203, and IDT7204

Functional Description

The CY7C419, CY7C420/1, CY7C424/5, CY7C428/9, and CY7C432/3 are first-in first-out (FIFO) memories offered in 600-mil wide and 300-mil wide packages. They are, respectively, 256, 512, 1,024, 2,048, and 4,096 words by 9-bits wide. Each FIFO memory is organized such that the data is read in the same sequential order that it was written. Full and Empty flags are provided to prevent overrun and underrun. Three additional pins are also provided to facilitate unlimited expansion in width, depth, or both. The depth expansion technique steers the control signals from one device to another in parallel, thus eliminating the serial addition of propagation delays, so that throughput is not reduced. Data is steered in a similar manner.

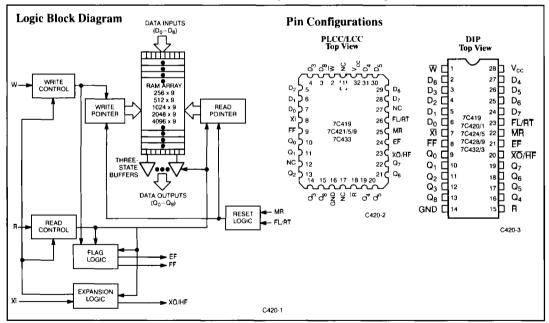
The read and write operations may be asynchronous; each can occur at a rate of 50.0 MHz. The write operation occurs when the write (\overline{W}) signal is LOW. Read occurs when read (\overline{R}) goes LOW. The nine

data outputs go to the high-impedance state when \overline{R} is HIGH.

A Half Full (HF) output flag is provided that is valid in the standalone and width expansion configurations. In the depth expansion configuration, this pin provides the expansion out (XO) information that is used to tell the next FIFO that it will be activated.

In the standalone and width expansion configurations, a LOW on the retransmit (\overline{RT}) input causes the FIFOs to retransmit the data. Read enable (\overline{R}) and write enable (\overline{W}) must both be HIGH during retransmit, and then \overline{R} is used to access the data.

The CY7C419, CY7C420, CY7C421, CY7C424, CY7C425, CY7C428, CY7C429, CY7C432, and CY7C433 are fabricated using an advanced 0.65-micron P-well CMOS technology. Input ESD protection is greater than 2000V and latch-up is prevented by careful layout and guard rines.



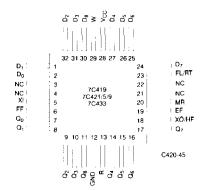


Selection Guide

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256 x 9	7C419-10	7C419-15	7C419-20	7C419-25	7C419-30	7C419-40	7C419-65
512 x 9 (600-mil only)			7C420-20	7C420-25	7C420-30	7C420-40	7C420-65
512 x 9	7C421-10	7C421-15	7C421-20	7C421-25	7C421-30	7C421-40	7C421-65
1K x 9 (600-mil only)			7C424-20	7C424+25	7C424-30	7C424-40	7C424-65
1K x 9	7C425-10	7C425-15	7C425-20	7C425-25	7C425-30	7C425-40	7C425-65
2K x 9 (600-mil only)			7C428-20	7C428-25	7C428-30	7C428-40	7C428-65
2K x 9	7C429-10	7C429-15	7C429-20	7C429-25	7C429-30	7C429-40	7C429-65
4K x 9 (600-mil only)				7C432-25	7C432-30	7C432-40	7C432-65
4K x 9	7C433-10	7C433-15	7C433-20	7C433-25	7C433-30	7C433-40	7C433-65
Frequency (MHz)	50	4()	33.3	28.5	25	20	12.5
Maximum Access Time (ns)	10	15	20	25	30	40	65
I _{CC1} (mA)	35	35	35	35	35	35	35

Pin Configurations (continued)

TQFP



Maximum Rating

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature -65° C to $+150^{\circ}$ C
Ambient Temperature with
Power Applied
Supply Voltage to Ground Potential0.5V to +7.0V
DC Voltage Applied to Outputs
in High Z State
DC Input Voltage0.5V to +7.0V
Power Dissipation 1.0W
Output Current, into Outputs (LOW)
Static Discharge Voltage
Latch-Up Current

Operating Range

Range	Ambient Temperature ^[1]	V _{CC}
Commercial	$0^{\circ}\text{C to} + 70^{\circ}\text{C}$	5V ± 10%
Industrial	~40°C to +85°C	5V ± 10%
Military	-55°C to +125°C	5V ± 10%

Electrical Characteristics Over the Operating Range^[2]

			7C420/1 - 10, 15 7C424/5 - 10, 15 7C428/9 - 10, 15	7C419-10, 15, 20, 25, 30, 40, 65 7C420/1-10, 15, 20, 25, 30, 40, 65 7C424/5-10, 15, 20, 25, 30, 40, 65 7C424/9-10, 15, 20, 25, 30, 40, 65 7C432/3-10, 15, 20, 25, 30, 40, 65		
Parameter	Description	Test Conditions	Min.	Max.	Unit	
V _{OH}	Output HIGH Voltage	$V_{\rm CC} = Min., I_{\rm OH} = -2.0 \mathrm{mA}$	24		V	
V _{OL}	Output LOW Voltage	$V_{CC} = Min., I_{OL} = 8.0 \text{ mA}$		0.4	V	
$V_{\rm IH}$	Input HIGH Voltage	Com'l	2.0	V _{CC}	V	
		Mil/Ind	2.2	V _{CC}	1 1	
V_{IL}	Input LOW Voltage		Note 3	0.8	V	
I _{IX}	Input Leakage Current	$GND \le V_1 \le V_{CC}$	-10	+10	μА	
loz	Output Leakage Current	$\overline{R} > V_{IH}, GND \le V_O \le V_{CC}$	-10	+10	μA	
I _{OS}	Output Short Circuit Current[4]	$V_{CC} = Max., V_{OUT} = GND$		-9()	mΑ	



Electrical Characteristics Over the Operating Range^[2] (continued)

				7C42 7C42	9-10 1-10 5-10 9-10 3-10	7C42 7C42 7C42	9-15 1-15 5-15 9-15 3-15	7C42 7C42 7C42 7C42 7C42 7C42	9-20 0-20 1-20 4-20 5-20 8-20 9-20	7C42 7C42 7C42 7C43	0-25 1-25 4-25 5-25 8-25 9-25	
Parameter	Description	Test Cond	itions	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
I_{CC}	Operating Current	$V_{CC} = Max.,$ $I_{OUT} = 0 \text{ mA}$	Com'l		85		65		55		50	mA
		$f = f_{MAX}$	Mil/Ind				100		90		80	
I _{CC1}	Operating Current	$V_{CC} = Max.,$ $I_{OUT} = 0 \text{ mA}$ F = 20 MHz	Com'l		35		35		35		35	mA
I _{SB1}	Standby Current	All Inputs =	Comʻl		10		10		10		10	mA
		V _{IH} Min.	Mil/Ind				15		15		15	1
I _{SB2}	Power-Down Current	All Inputs ≥	Com'l		5		5		5	<u> </u>	5	mA
		$V_{CC} = 0.2V$	Mil/Ind	ļ			8		8		8	1

Electrical Characteristics Over the Operating Range^[2] (continued)

				7C42 7C42 7C42 7C42 7C42 7C42 7C43	9-30 0-30 1-30 4-30 5-30 8-30 9-30 2-30 3-30	7C42 7C42 7C42 7C42 7C42 7C42 7C43	1-40 4-40 5-40	7C42 7C42 7C42 7C42 7C42 7C42 7C43	9-65 0-65 1-65 4-65 5-65 8-65 9-65 2-65 3-65	
Parameter	Parameter Description		tions	ions Min. Max.		Min.	Max.	Min.	Max.	Units
I_{CC}	Operating Current	$V_{CC} = Max.,$	Com'l		40		35		35	mA
		$I_{OUT} = 0 \text{ mA}$ $f = f_{MAX}$	Mil/Ind		75		70		65	
I _{CC1}	Operating Current	$V_{CC} = Max.,$ $I_{OUT} = 0 \text{ mA}$ $F = 20 \text{ MHz}$	Com'l		35		35		35	mA
I _{SB1}	Standby Current	All Inputs =	Com'l		10		10		10	mA
		V _{IH} Min.	Mil		15		15		15	1
I _{SB2}	Power-Down Current	All Inputs ≥	Com'l		5		5		5	mA
		$V_{CC} = 0.2V$	Mil	1	8		8		8	1

Capacitance^[5]

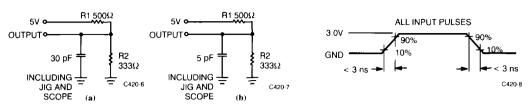
Parameter Description		Test Conditions	Max.	Unit
C _{IN}	Input Capacitance	$T_A = 25^{\circ}C$, $f = 1$ MHz,	6	pF
C _{OUT}	Output Capacitance	$V_{CC} = 4.5V$	6	pF

Notes:

- 1. T_A is the "instant on" case temperature.
 2. See the last page of this specification for Group A subgroup testing information.
- 3 V_{IL} (Min.) = -2.0V for pulse durations of less than 20 ns.
- For test purposes, not more than one output at a time should be shorted. Short circuit test duration should not exceed 30 seconds.
- Tested initially and after any design or process changes that may affect these parameters.



AC Test Loads and Waveforms



THÉVENIN EQUIVALENT Equivalent to:

Switching Characteristics Over the Operating Rangelo, 71

		7C41	9-10	7C41	9-15	7C41 7C42	9-20 0-20		9-25 0-25	
		7C42	7C421-10 7C425-10 7C429-10		7C421-15 7C425-15 7C429-15		7C421-20 7C424-20 7C425-20 7C428-20 7C429-20		1-25 4-25 5-25 8-25 9-25	
		7C433-10		7C433-15		7C433-20		7C432-25 7C433-25		
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
t _{RC}	Read Cycle Time	20		25		30		35		ns
tA	Access Time	T	10		15		20		25	ns
t _{RR}	Read Recovery Time	10		10		10		10		ns
tPR	Read Pulse Width	10		15		20		25		ns
t _{LZR} [5.8]	Read LOW to Low Z	3		3		3		3		ns
t _{DVR} [8,9]	Data Valid After Read HIGH	5		5		5		5		ns
t _{HZR} [5,8,9]	Read HIGH to High Z		15		15		15		18	ns
twc	Write Cycle Time	20		25		30		35		ns
tpW	Write Pulse Width	10		15		20		25		ns
t _{HWZ} [5,8]	Write HIGH to Low Z	5		5		5		5		ns
twr	Write Recovery Time	10		10		10		10		ns
t _{SD}	Data Set-Up Time	6		8		12		15		ns
tHD	Data Hold Time	0		0		()		()		ns
† _{MRSC}	MR Cycle Time	20		25		30		35		ns
t _{PMR}	MR Pulse Width	10		15		20		25		ns
t _{RMR}	MR Recovery Time	10		10		10		10		ns
t _{RPW}	Read HIGH to MR HIGH	10		15		20		25		ns
twpw	Write HIGH to MR HIGH	10		15		20		25		ns
tric	Retransmit Cycle Time	20		25		3()		35		ns
tpRT	Retransmit Pulse Width	10		15		20		25		ns
tRTR	Retransmit Recovery Time	10		10		10		10		ns

- rest Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5V and output loading of the specified $I_{\rm OI}/I_{\rm OI}$ and 30 pF load capacitance, as in part (a) of AC Test Load and Waveforms, unless otherwise specified.
- See the last page of this specification for Group A subgroup testing information.
- t_{HZR} transition is measured at + 200 mV from V_{OH} and ~ 200 mV from V_{OH} transition is measured at the 1.5V level, t_{HWZ} and t_{LZR} transition is measured at \pm 100 mV from the steady state.
- $t_{\rm HZR}$ and $t_{\rm DVR}$ use capacitance loading as in part (b) of AC Test Load and Waveforms.



		7C419-10 7C419-15 7C421-10 7C421-15 7C425-10 7C425-15 7C429-10 7C429-15 7C433-10 7C433-15		7C42 7C42 7C42 7C42 7C42 7C42	9-20 0-20 1-20 4-20 5-20 8-20 9-20	-20				
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
tefl	MR to EF LOW		20		25		30		35	ns
t _{HFH}	MR to HF HIGH		20		25		30		35	ns
tppH	MR to FF HIGH		20		25		30		35	ns
t _{REF}	Read LOW to EF LOW		10		15		20		25	ns
t _{RFF}	Read HIGH to FF HIGH		10		15		20		25	ns
tweF	Write HIGH to EF HIGH		10		15		20		25	ns
t _{WFF}	Write LOW to FF LOW	<u> </u>	10		15		20		25	ns
twhF	Write LOW to HF LOW		10		15		20		25	ns
t _{RHF}	Read HIGH to HF HIGH		10		15		20		25	ns
1 _{RAE}	Effective Read from Write HIGH		10		15		20		25	ns
t _{RPE}	Effective Read Pulse Width After EF HIGH	10		15		20		25		ns
t _{WAF}	Effective Write from Read HIGH		10		15		20		25	ns
t _{WPF}	Effective Write Pulse Width After FF HIGH	10		15		20		25		ns
t _{XOL}	Expansion Out LOW Delay from Clock		10		15		20		25	ns
t _{XOH}	Expansion Out HIGH Delay from Clock		10		15		20		25	ns



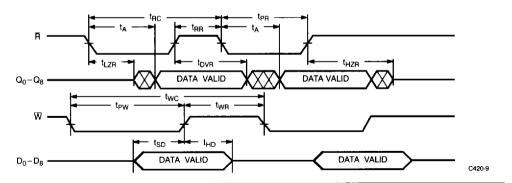
Switching Characteristics Over the Operating Range^[6, 7] (continued)

			7C419-30 7C420-30 7C421-30 7C424-30 7C425-30 7C428-30 7C429-30 7C432-30 7C433-30		7C419 - 40 7C420 - 40 7C421 - 40 7C424 - 40 7C425 - 40 7C428 - 40 7C429 - 40 7C432 - 40 7C433 - 40		7C419-65 7C420-65 7C421-65 7C424-65 7C425-65 7C428-65 7C429-65 7C432-65 7C433-65	
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Unit
t_{RC}	Read Cycle Time	40		50		80		ns
t_{A}	Access Time	<u> </u>	30		40		65	ns
t _{RR}	Read Recovery Time	10		10		15		ns
tPR	Read Pulse Width	30		40		65		ns
t _{LZR} [5.8]	Read LOW to Low Z	3		3		3		ns
t _{DVR} [8,9]	Data Valid After Read HIGH	5		5		5		ns
t _{HZR} [5,8,9]	Read HIGH to High Z		20		20		20	ns
twc	Write Cycle Time	40		50		80		ns
tpw	Write Pulse Width	30		40		65		ns
t _{HWZ} [5,8]	Write HIGH to Low Z	5		5		5		ns
twR	Write Recovery Time	10		10		15		ns
t_{SD}	Data Set-Up Time	18		20		30		ns
tHD	Data Hold Time	0		0		0		ns
1 _{MRSC}	MR Cycle Time	40		50		80		ns
1 _{PMR}	MR Pulse Width	30		40	_	65		ns
trmr	MR Recovery Time	10		10		15		ns
t _{RPW}	Read HIGH to MR HIGH	30		40		65		ns
twpw	Write HIGH to MR HIGH	30		40		65		ns
t _{RTC}	Retransmit Cycle Time	40		50		80		ns
tPRT	Retransmit Pulse Width	30		40		65	T	ns
t _{RTR}	Retransmit Recovery Time	10		10		15		ns
tert	MR to EF LOW		40		50		80	ns
tillill	MR to HF HIGH		40		50		80	ns
1 _{FFH}	MR to FF HIGH	1	40		50		80	ns
t _{REF}	Read LOW to EF LOW		30		35		60	ns
tREF	Read HIGH to FF HIGH		30		35		60	ns
twer	Write HIGH to EF HIGH	1	30		35		60	ns
twee	Write LOW to FF LOW	İ	30		35		60	ns
twiff	Write LOW to HF LOW		30		35		60	ns
t _{RHF}	Read HIGH to HF HIGH		30		35		60	ns
t _{RAI} .	Effective Read from Write HIGH	<u> </u>	30		35		60	ns
t _{RPI:}	Effective Read Pulse Width After EF HIGH	30		40		65	<u> </u>	ns
IWAF	Effective Write from Read HIGH	\vdash	30		35		60	ns
twpp	Effective Write Pulse Width After FF HIGH	30	 	40		65		ns
†NOL	Expansion Out LOW Delay from Clock	1	30	1	40	 	65	ns
†NOH	Expansion Out HIGH Delay from Clock	+	30	-	40	1	65	ns

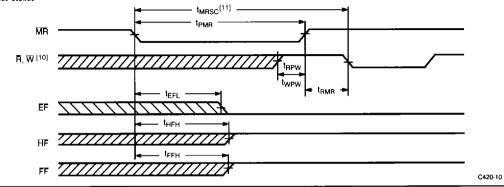


Switching Waveforms

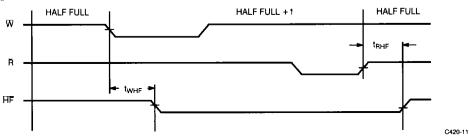
Asynchronous Read and Write



Master Reset



Half-Full Flag



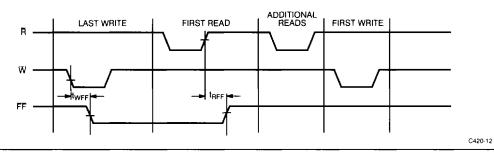
11. $t_{MRSC} = t_{PMR} + t_{RMR}$.

C420-13

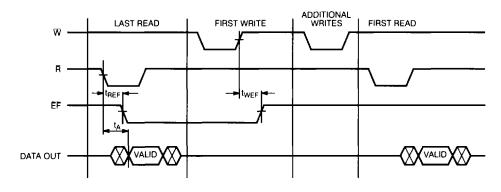


Switching Waveforms (continued)

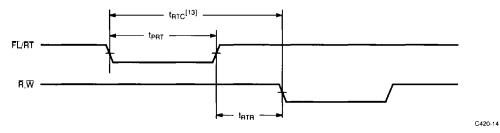
Last Write to First Read Full Flag



Last Read to First Write Empty Flag



 $Retransmit^{[12]}$

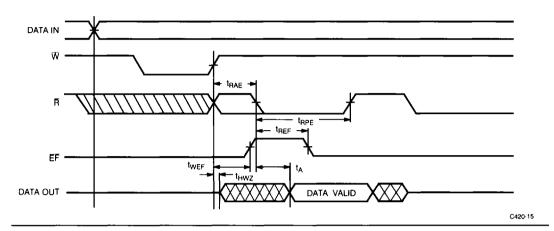


Notes: 12. EF, HF and FF may change state during retransmit as a result of the offset of the read and write pointers, but flags will be valid at t_{RTC} . 13. $t_{RTC} = t_{PR1} + t_{RTR}$.

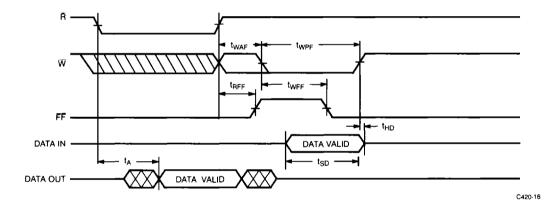


Switching Waveforms (continued)

Empty Flag and Read Data Flow-Through Mode



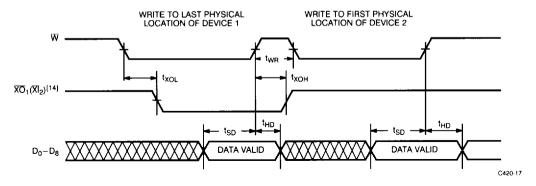
Full Flag and Write Data Flow-Through Mode

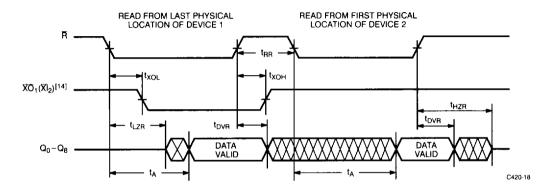




Switching Waveforms (continued)

Expansion Timing Diagrams





Note:

Expansion Out of device 1 (XO₁) is connected to Expansion In of device 2 (XI₂).



Architecture

The CY7C419, CY7C420/1, CY7C424/5, CY7C428/9, CY7C432/3 FIFOs consist of an array of 256, 512, 1024, 2048, 4096 words of 9 bits each (implemented by an array of dual-port RAM cells), a read pointer, a write pointer, control signals (W, R, XI, XO, FL, RT, MR), and Full, Half Full, and Empty flags.

Dual-Port RAM

The dual-port RAM architecture refers to the basic memory cell used in the RAM. The cell itself enables the read and write operations to be independent of each other, which is necessary to achieve truly asynchronous operation of the inputs and outputs. A second benefit is that the time required to increment the read and write pointers is much less than the time that would be required for data propagation through the memory, which would be the case if the memory were implemented using the conventional register array architecture.

Resetting the FIFO

Upon power-up, the FIFO must be reset with a Master Reset (\$\overline{MR}\$) cycle. This causes the FIFO to enter the empty condition signified by the Empty flag (\$\overline{EF}\$) being LOW, and both the Half Full (\$\overline{HF}\$) and Full flags (\$\overline{FF}\$) being HIGH. Read (\$\overline{R}\$) and write (\$\overline{W}\$) must be HIGH t_{RPW}/t_{WPW} before and t_{RMR} after the rising edge of \overline{MR} for a valid reset cycle. If reading from the FIFO after a reset cycle is attempted, the outputs will all be in the high-impedance state.

Writing Data to the FIFO

The availability of at least one empty location is indicated by a HIGH FF. The falling edge of $\overline{\mathbf{W}}$ initiates a write cycle. Data appearing at the inputs $(D_0 - D_8)$ t_{SD} before and t_{HD} after the rising edge of $\overline{\mathbf{W}}$ will be stored sequentially in the FIFO.

The \overline{EF} LOW-to-HIGH transition occurs t_{WFF} after the first LOW-to-HIGH transition of \overline{W} for an empty FIFO. HF goes LOW t_{WHF} after the falling edge of \overline{W} following the FIFO actually being Half Full. Therefore, the \overline{HF} is active once the FIFO is filled to half its capacity plus one word. \overline{HF} will remain LOW while less than one half of total memory is available for writing. The LOW-to-HIGH transition of \overline{HF} occurs t_{RHF} after the rising edge of \overline{R} when the FIFO goes from half full +1 to half full. \overline{HF} is available in standalone and width expansion modes. \overline{FF} goes LOW t_{WFF} after the falling edge of \overline{W} , during the cycle in which the last available location is filled. Internal logic prevents overrunning a full FIFO. Writes to a full FIFO are ignored and the write pointer is not incremented. \overline{FF} goes HIGH t_{RFF} after a read from a full FIFO.

Reading Data from the FIFO

The falling edge of \overline{R} initiates a read cycle if the \overline{EF} is not LOW. Data outputs (Q_0-Q_8) are in a high-impedance condition between read operations $(\overline{R}|HIGH)$, when the FIFO is empty, or when the FIFO is not the active device in the depth expansion mode.

When one word is in the FIFO, the falling edge of \overline{R} initiates a HIGH-to-LOW transition of $\overline{E}\overline{F}$. The rising edge of \overline{R} causes the data outputs to go to the high-impedance state and remain such until a write is performed. Reads to an empty FIFO are ignored and do not increment the read pointer. From the empty condition, the FIFO can be read t_{WFF} after a valid write.

The retransmit feature is beneficial when transferring packets of data. It enables the receipt of data to be acknowledged by the receiver and retransmitted if necessary.

The Retransmit (\overline{RT}) input is active in the standalone and width expansion modes. The retransmit feature is intended for use when a number of writes equal to or less than the depth of the FIFO have occurred since the last \overline{MR} cycle. A LOW pulse on \overline{RT} resets the

internal read pointer to the first physical location of the FIFO. \overline{R} and \overline{W} must both be HIGH while and t_{RTR} after retransmit is LOW. With every read cycle after retransmit, previously accessed data as well as not previously accessed data is read and the read pointer is incremented until it is equal to the write pointer. Full, Half Full, and Empty flags are governed by the relative locations of the read and write pointers and are updated during a retransmit cycle. Data written to the FIFO after activation of \overline{RT} are transmitted also.

Up to the full depth of the FIFO can be repeatedly retransmitted.

Standalone/Width Expansion Modes

Standalone and width expansion modes are set by grounding Expansion In (\overline{XI}) and tying First Load (\overline{FL}) to V_{CC} . FIFOs can be expanded in width to provide word widths greater than nine in increments of nine. During width expansion mode, all control line inputs are common to all devices, and flag outputs from any device can be monitored.

Depth Expansion Mode (see Figure 1)

Depth expansion mode is entered when, during a \overline{MR} cycle, Expansion Out (\overline{XO}) of one device is connected to Expansion In (\overline{XI}) of the next device, with \overline{XO} of the last device connected to \overline{XI} of the first device. In the depth expansion mode the First Load (\overline{FL}) in put, when grounded, indicates that this part is the first to be loaded. All other devices must have this pin HIGH. To enable the correct FIFO, \overline{XO} is pulsed LOW when the last physical location of the previous FIFO is written to and pulsed LOW again when the last physical location is read. Only one FIFO is enabled for read and one for write at any given time. All other devices are in standby.

FIFOs can also be expanded simultaneously in depth and width. Consequently, any depth or width FIFO can be created of word widths in increments of 9. When expanding in depth, a composite FF must be created by ORing the FFs together. Likewise, a composite EF is created by ORing the EFs together. HF and RT functions are not available in depth expansion mode.

Use of the Empty and Full Flags

In order to achieve the maximum frequency, the flags must be valid at the beginning of the next cycle. However, because they can be updated by either edge of the read of write signal, they must be valid by one-half of a cycle. Cypress FIFOs meet this requirement; some competitors' FIFOs do not.

The reason why the flags are required to be valid by the next cycle is fairly complex. It has to do with the "effective pulse width violation" phenomenon, which can occur at the full and empty boundary conditions, if the flags are not properly used. The empty flag must be used to prevent reading from an empty FIFO and the full flag must be used to prevent writing into a full FIFO.

For example, consider an empty FIFO that is receiving read pulses. Because the FIFO is empty, the read pulses are ignored by the FIFO, and nothing happens. Next, a single word is written into the FIFO, with a signal that is asynchronous to the read signal. The (internal) state machine in the FIFO goes from empty to empty+1. However, it does this asynchronously with respect to the read signal, so that it cannot be determined what the effective pulse width of the read signal is, because the state machine does not look at the read signal until it goes to the empty+1 state. In a similar manner, the minimum write pulse width may be violated by attempting to write into a full FIFO, and asynchronously performing a read. The empty and full flags are used to avoid these effective pulse width violations, but in order to do this and operate at the maximum frequency, the flag must be valid at the beginning of the next cycle.



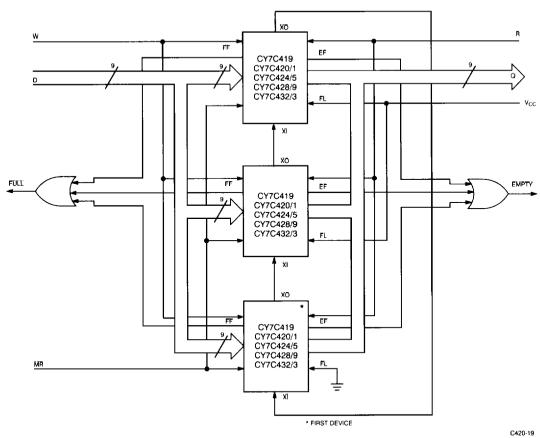
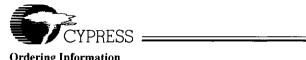


Figure 1. Depth Expansion



Ordering Information

Speed (ns)	Ordering Code	Package Type	Package Type	Operating Range
10	CY7C419-10AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C419-10JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C419-10PC	P21	28-Lead (300-Mil) Molded DIP	Í
	CY7C419-10VC	V21	28-Lead (300-Mil) Molded SOJ	
15	CY7C419-15AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C419~15JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C419-15PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C419-15VC	V21	28-Lead (300-Mil) Molded SOJ	Ì
	CY7C419-15JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C419-15PI	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C419-15VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C419-15DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C419-15LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
20	CY7C419-20AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C419-20JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C419-20PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C419~20VC	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C419-20JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C419+20PI	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C419+20VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C419-20DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C419-20LMB	L55	32-Pin Rectangular Leadless Chip Carrier	1
25	CY7C419-25AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C419-25JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C419-25PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C419-25VC	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C419-25JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C419-25PI	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C419-25VI	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C419-25DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C419-25LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
30	CY7C419~30AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C419-30JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C419-30PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C419-30VC	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C419-30JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C419-30PI	P21	28-Lead (300-Mil) Molded DIP]
	CY7C419-30VI	V21	28-Lead (300-Mil) Molded SOJ	L
	CY7C419-30DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C419-30LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
40	CY7C419-40AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C419-40JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C419-40PC	P21	28-Lead (300-Mil) Molded DIP]
	CY7C419-40VC	V21	28-Lead (300-Mil) Molded SOJ]



Speed (ns)	Ordering Code	Package Type	Package Type	Operating Range
	CY7C419-40JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C419-40PI	P21	28-Lead (300-Mil) Molded DIP	
	CY7C419-40VI	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C419-40DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C419-40LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
65	65 CY7C419-65AC		32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C419-65JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C419-65PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C419-65VC	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C419-65JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C419-65PI	P21	28-Lead (300-Mil) Molded DIP	
	CY7C419-65VI	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C419-65DMB		28-Lead (300-Mil) CerDIP	Military
	CY7C419-65LMB	L55	32-Pin Rectangular Leadless Chip Carrier	

Speed (ns)	Ordering Code	Package Type	Package Type	Operating Range
20	CY7C420-20PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
25	CY7C420-25PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
	CY7C420-25PI	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C420-25DMB	D16	28-Lead (600-Mil) CerDIP	Military
30	CY7C420-30PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
	CY7C420-30PI	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C420-30DMB	D16	28-Lead (600-Mil) CerDIP	Military
40	CY7C420-40PC	P15	28-Lead (600-Mil) Molded DIP	Commerical
	CY7C420-40PI	P15	28-Lead (600-Mil) Molded DIP	Industry
	CY7C420-40DMB	D16	28-Lead (600-Mil) CerDIP	Military
65	CY7C420-65PC	P15	28-Lead (600-Mil) Molded DIP	Commerical
	CY7C420-65PI	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C420-65DMB	D16	28-Lead (600-Mil) CerDIP	Military



Speed (ns)	Ordering Code	Package Type	Package Type	Operating Range
10	CY7C421-10AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C421 - 10JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C421-10PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C421-10VC	V21	28-Lead (300-Mil) Molded SOJ	1
15	CY7C421-15AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C421 - 15JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C421-15PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C421-15VC	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C421-15JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C421-15PI	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C421-15VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C421-15DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C421-15LMB	L55	32-Pin Rectangular Leadless Chip Carrier	1
20	CY7C421-20AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C421-20JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C421-20PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C421-20VC	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C421-20JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C421-20PI	P21	28-Lead (300-Mil) Molded DIP	
	CY7C421-20VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C421-20DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C421-20LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
25	CY7C421-25AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C421-25JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C421-25PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C421-25VC	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C421-25J1	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C421-25PI	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C421-25VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C421-25DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C421-25LMB	L55	32-Pin Rectangular Leadless Chip Carrier	1
30	CY7C421-30AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C421-30JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C421-30PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C421-30VC	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C421-30JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C421-30PI	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C421-30VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C421-30DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C421-30LMB	L55	32-Pin Rectangular Leadless Chip Carrier	1



Speed (ns)	Ordering Code	Package Type	Package Type	Operating Range
4()	CY7C421-40AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C421-40JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C421-40PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C421-40VC	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C421-40JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C421-40PI	P21	28-Lead (300-Mil) Molded DIP	
	CY7C421-40VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C421-40DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C421-40LMB	1.55	32-Pin Rectangular Leadless Chip Carrier	1
65	CY7C421-65AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C421-40JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C421-65PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C421-65VC	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C421-65JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C421-65PI	P21	28-Lead (300-Mil) Molded DIP]
	CY7C421-65VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C421-65DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C421-65LMB	L55	32-Pin Rectangular Leadless Chip Carrier	1

Speed (ns)	Ordering Code	Package Type	Package Type	Operating Range
20	CY7C424-20PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
25	CY7C424-25PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
	CY7C424-25PI	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C424-25DMB	D16	28-Lead (600-Mil) CerDIP	Military
30	CY7C424-30PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
	CY7C424-30PI	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C424+30DMB	D16	28-Lead (600-Mil) CerDIP	Military
40	CY7C424-40PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
	CY7C424-40PI	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C424-40DMB	D16	28-Lead (600-Mil) CerDIP	Military
65	CY7C424-65PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
	CY7C424-65Pl	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C424-65DMB	D16	28-Lead (600-Mil) CerDIP	Military



Speed (ns)	Ordering Code	Package Type	Package Type	Operating Range
10	CY7C425-10AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C425-10JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C425-10PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C425-10VC	V21	28-Lead (300-Mil) Molded SOJ	
15	CY7C425-15AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C425-15JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C425-15PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C425-15VC	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C425-15JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C425-15PI	P21	28-Lead (300-Mil) Molded DIP	
	CY7C425 - 15VI	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C425-15DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C425-15LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
20	CY7C425-20AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C425-20JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C425-20PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C425-20VC	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C425-20J1	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C425-20PI	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C425-20VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C425-20DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C425-20LMB	L55	32-Pin Rectangular Leadless Chip Carrier	1
25	CY7C425-25AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C425-25JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C425-25PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C425-25VC	V21	28-Lead (300-Mil) Molded SOJ]
	CY7C425-25JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C425-25PI	P21	28-Lead (300-Mil) Molded DIP	
	CY7C425-25VI	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C425-25DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C425-25LMB	L55	32-Pin Rectangular Leadless Chip Carrier	1
30	CY7C425-30AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C425-30JC	J65	32-Lead Plastic Leaded Chip Carrier]
	CY7C425-30PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C425-30VC	V21	28-Lead (300-Mil) Molded SOJ	<u></u>
	CY7C425-30J1	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C425-30PI	P21	28-Lead (300-Mil) Molded DIP]
	CY7C425-30VI	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C425-30DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C425-30LMB	L55	32-Pin Rectangular Leadless Chip Carrier	



Speed (ns)	Ordering Code	Package Type	Package Type	Operating Range
40	CY7C425-40AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C425-40JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C425-40PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C425-40VC	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C425-40JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C425~40PI	P21	28-Lead (300-Mil) Molded DIP	
	CY7C425-40VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C425-40DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C425-40LMB	1.55	32-Pin Rectangular Leadless Chip Carrier	1
65	CY7C425+65AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C425-65JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C425~65PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C425~65VC	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C425+65JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C425-65P1	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C425=65VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C425-65DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C425+65LMB	L55	32-Pin Rectangular Leadless Chip Carrier	1

Speed (ns)	Ordering Code	Package Type	Package Type	Operating Range
20	CY7C428-20PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
25	CY7C428+25PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
	CY7C428+25PI	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C428-25DMB	D16	28-Lead (600-Mil) CerDIP	Military
30	CY7C428+30PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
	CY7C428=30PI	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C428-30DMB	D16	28-Lead (600-Mil) CerDIP	Military
40	CY7C428-40PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
	CY7C428-40PI	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C428-40DMB	D16	28-Lead (600-Mil) CerDIP	Military
65	CY7C428-65PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
	CY7C428-65PI	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C428=65DMB	D16	28-Lead (600-Mil) CerDIP	Military



Speed (ns)	Ordering Code	Package Type	Package Type	Operating Range
10	CY7C429-10AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C429-10JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C429-10PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C429-10VC	V21	28-Lead (300-Mil) Molded SOJ	1
15	CY7C429-15AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C429-15JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C429-15PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C429-15VC	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C429+15J1	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C429-15PI	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C429-15VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C429-15DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C429-15LMB	L55	32-Pin Rectangular Leadless Chip Carrier	1
20	CY7C429-20AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C429-20JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C429-20PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C429-20VC	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C429-20J1	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C429-20PI	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C429-20VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C429-20DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C429-20LMB	L55	32-Pin Rectangular Leadless Chip Carrier	1
25	CY7C429-25AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C429-25JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C429-25PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C429-25VC	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C429-25JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C429-25PI	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C429-25VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C429+25DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C429-25LMB	L55	32-Pin Rectangular Leadless Chip Carrier	1
30	CY7C429-30AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C429-30JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C429-30PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C429-30VC	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C429-30JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C429-30PI	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C429-30VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C429-30DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C429-30LMB	L55	32-Pin Rectangular Leadless Chip Carrier	1
40	CY7C429-40AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C429-40JC	J65	32-Lead Plastic Leaded Chip Carrier	1
	CY7C429-40PC	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C429-40VC	V21	28-Lead (300-Mil) Molded SOJ	1



Speed (ns)	Ordering Code	Package Type	Package Type	Operating Range
40	CY7C429-40JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C429-40PI	P21	28-Lead (300-Mil) Molded DIP	1
	CY7C429-40VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C429-40DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C429-40LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
65	CY7C429-65AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C429-65JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C429-65PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C429-65VC	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C429-65JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C429-65PI	P21	28-Lead (300-Mil) Molded DIP	
	CY7C429-65VI	V21	28-Lead (300-Mil) Molded SOJ	1
	CY7C429-65DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C429-65LMB	1.55	32-Pin Rectangular Leadless Chip Carrier	1

Ordering Information (continued)

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
25	CY7C432-25PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
30	CY7C432-30PC	P15	28-Lead (600-Mil) Molded DIP	Commerical
	CY7C432-30PI	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C432-30DMB	D16	28-Lead (600-Mil) CerDIP	Military
40	CY7C432-40PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
	CY7C432-40PI	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C432-40DMB	D16	28-Lead (600-Mil) CerDIP	Military
65	CY7C432-65PC	P15	28-Lead (600-Mil) Molded DIP	Commercial
	CY7C432-65PI	P15	28-Lead (600-Mil) Molded DIP	Industrial
	CY7C432-65DMB	D16	28-Lead (600-Mil) CerDIP	Military

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
10	CY7C433-10AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C433-10JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C433-10PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C433-10VC	V21	28-Lead (300-Mil) Molded SOJ	
15	CY7C433=15AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercial
	CY7C433-15JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C433-15PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C433-15VC	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C433-15JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C433-15PI	P21	28-Lead (300-Mil) Molded DIP	
	CY7C433-15VI	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C433-15DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C433-15LMB	L55	32-Pin Rectangular Leadless Chip Carrier	



Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
20	CY7C433-20AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C433-20JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C433-20PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C433-20VC	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C433-20JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C433-20Pl	P21	28-Lead (300-Mil) Molded DIP	
	CY7C433-20VI	V21	28-Lead (300-Mil) Molded SOJ	-
	CY7C433-20DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C433-20LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
25	CY7C433+25AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C433-25JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C433-25PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C433+25VC	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C433-25JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C433-25Pl	P21	28-Lead (300-Mil) Molded DIP	
	CY7C433-25VI	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C433-25DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C433-25LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
30	CY7C433-30AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C433-30JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C433-30PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C433-30VC	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C433-30JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C433-30PI	P21	28-Lead (300-Mil) Molded DIP	
	CY7C433=30VI	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C433-30DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C433-30LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
4()	CY7C433-40AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C433-40JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C433-40PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C433-40VC	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C433+40JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C433-40PI	P21	28-Lead (300-Mil) Molded DIP	
	CY7C433-40VI	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C433-40DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C433-40LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
65	CY7C433-65AC	A32	32-Pin Thin Plastic Quad Flatpack	Commercia
	CY7C433-65JC	J65	32-Lead Plastic Leaded Chip Carrier	
	CY7C433-65PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C433-65VC	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C433-65JI	J65	32-Lead Plastic Leaded Chip Carrier	Industrial
	CY7C433-65PI	P21	28-Lead (300-Mil) Molded DIP	
	CY7C433-65VI	V21	28-Lead (300-Mil) Molded SOJ	
	CY7C433-65DMB	D22	28-Lead (300-Mil) CerDIP	Military
	C 17C 455 05151115			



MILITARY SPECIFICATIONS Group A Subgroup Testing DC Characteristics

Parameters	Subgroups
V_{OH}	1, 2, 3
V_{OL}	1, 2, 3
$V_{ m lH}$	1, 2, 3
V _{IL} Max.	1, 2, 3
I _{fX}	1, 2, 3
I_{CC}	1, 2, 3
1_{CC1}	1, 2, 3
I_{SB1}	1, 2, 3
l _{SB2}	1, 2, 3
I _{OS}	1, 2, 3

Switching Characteristics

Parameters	Subgroups
t _{RC}	9, 10, 11
t _A	9, 10, 11
t _{RR}	9, 10, 11
t _{PR}	9, 10, 11
t _{DVR}	9, 10, 11
twc	9, 10, 11
t _{PW}	9, 10, 11
twR	9, 10, 11
t _{SD}	9, 10, 11
t _{HD}	9, 10, 11
t _{MRSC}	9, 10, 11
t _{PMR}	9, 10, 11
1 _{RMR}	9, 10, 11
trpw	9, 10, 11
twpw	9, 10, 11
t _{RTC}	9, 10, 11
tpRT	9, 10, 11
t _{RTR}	9, 10, 11
tEFL	9, 10, 11
tHFH	9, 10, 11
t _{FFH}	9, 10, 11
t _{REF}	9, 10, 11
t _{RFF}	9, 10, 11
twee	9, 10, 11
t _{WFF}	9, 10, 11
twhF	9, 10, 11
t _{RHF}	9, 10, 11
t _{RAE}	9, 10, 11
t _{RPE}	9, 10, 11
twaF	9, 10, 11
twpF	9, 10, 11
t _{XOL}	9, 10, 11
t _{XOH}	9, 10, 11

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